

# 5S Battery Protector with State of Charge Indication

## Advance Information NCS35011

The NCS35011 is an ultra-low power protection integrated circuit managing lithium-ion batteries from 3 to 5 cells in series with accurate battery voltage indication up to 5 LED outputs.

Each cell in the battery pack is monitored for an over-voltage and under-voltage condition. Upon detecting an over-voltage, the ODI pin will assert indicating a fault condition and stay asserted until the fault is cleared. During an under voltage condition, the UDI pin will also assert indicating the fault but will have a pulse width that is pre-set in the protector. Both over and under voltage detections have a hard coded pre-set delay time before fault indication.

Pulling the ENB high will start a measurement of the battery pack voltage which will be compared to a pre-set detection threshold table. If a threshold voltage is exceeded the protector will power the corresponding LED to indicate state of charge of the pack.

Hardware protection and battery monitoring run autonomously and allows operation without a microcontroller.

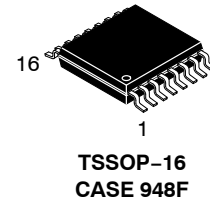
### Features

- Over-Voltage (OV) and Under-Voltage (UV) Detection
- Protection for 3, 4 and 5 Series Cells
- State of Charge (SoC) Indication with High Voltage Tolerant LED Drivers
- Configurable Fault Outputs (Active High or Low for Push-Pull or Open Drain)
- High-Accuracy Voltage Measurement  $\pm 5$  mV
- Low Power Consumption  $I_{CC} = 4 \mu A$
- Input BAT Voltage Range 5 V to 28 V, tolerant to 70 V for Increased Immunity to Surge
- Extended Junction Temperature Range to 125°C
- These Devices are Pb-Free and are RoHS Compliant

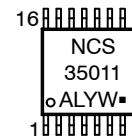
### Applications

- Secondary Protection
- Power and Gardening Tools
- Portable/Autonomous Equipment (Cleaners, Mowers, Motive, Medical)

This document contains information on a new product. Specifications and information herein are subject to change without notice.

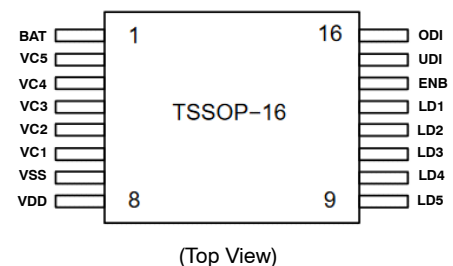


### MARKING DIAGRAM



NCS35011 = Specific Device Code  
 A = Assembly Location  
 L = Wafer Lot  
 Y = Year  
 W = Work Week  
 ■ = Pb-Free Package

### PIN CONNECTIONS



### ORDERING INFORMATION

Device	Package	Shipping <sup>†</sup>
NCS35011DTBR2G	TSSOP-16 (Pb-Free)	2500 / Tape & Reel

<sup>†</sup>For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

# NCS35011

## Block Diagram

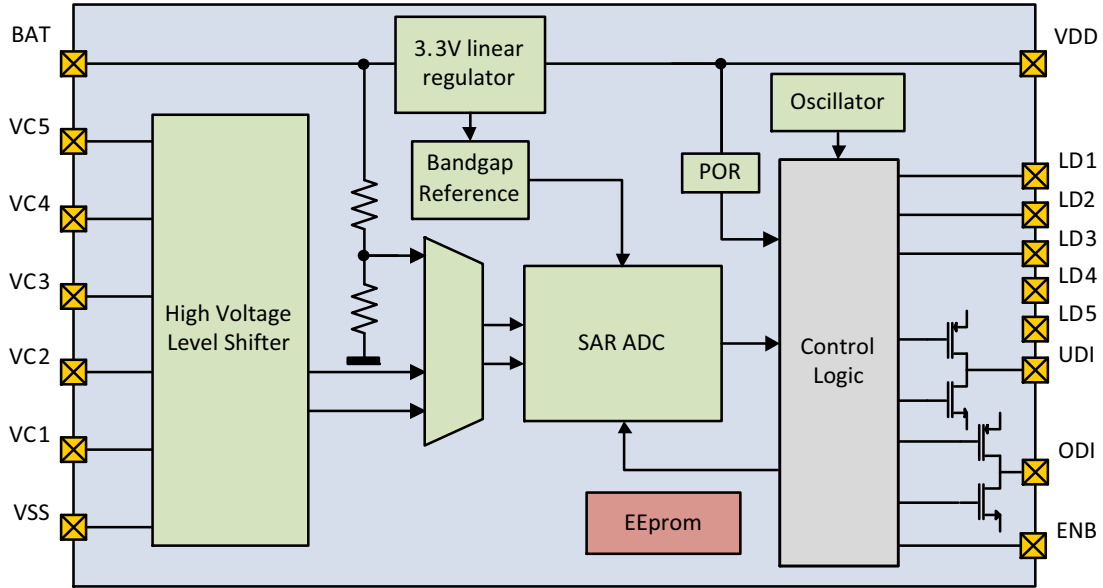


Figure 1. Simplified Block Diagram

## Pin Connections

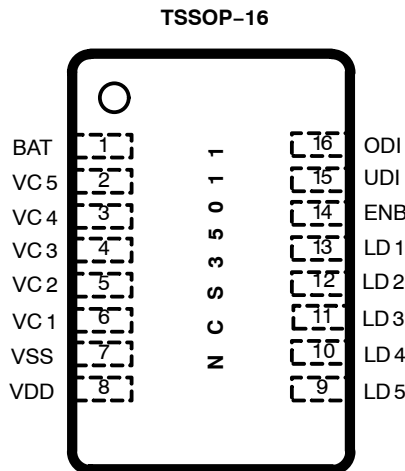


Figure 2. NCS35011 Pinout (TSSOP-16)

## PIN DESCRIPTION

Signal Name	Pin No.	Type	Description
BAT	1	Power	Positive Battery input voltage
VC5	2	Analog	Battery cell 5 voltage
VC4	3	Analog	Battery cell 4 voltage
VC3	4	Analog	Battery cell 3 voltage
VC2	5	Analog	Battery cell 2 voltage
VC1	6	Analog	Battery cell 1 voltage
VSS	7	Ground	Negative Battery input voltage
VDD	8	Power	3.3 V regulator output voltage
LD5	9	Output Open Drain	LED output 5, open drain; active low

# NCS35011

## PIN DESCRIPTION (continued)

Signal Name	Pin No.	Type	Description
LD4	10	Output Open Drain	LED output 4, open drain; active low
LD3	11	Output Open Drain	LED output 3, open drain; active low
LD2	12	Output Open Drain	LED output 2, open drain; active low
LD1	13	Output Open Drain	LED output 1, open drain; active low
ENB	14	Input	LED output indication enable input; pull down, active high
UDI	15	Output	Cell Under voltage detection output indication; configurable (CMOS active low or high; nFET open drain active on or off)
ODI	16	Output	Cell over voltage detection output indication; configurable (CMOS active low or high; nFET open drain active on or off)

## ABSOLUTE MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input voltage (Note 1)	$V_{BAT}$	-0.5 to 70	V
Supply Current	$I_{BAT}$	10	mA
VC1, VC2, VC3, VC4, VC5, ODI, UDI, LD1, LD2, LD3, LD4, LD5 voltage	$V_{IHV}$	-0.5 to 70	V
ENB, NC voltage	$V_{ILV}$	$V_{BAT}$	V
VCn - VCn-1 differential cell input voltages	$V_{CELLD}$	-0.5 to 30	V
Maximum Junction Temperature	$T_{J(max)}$	125	°C
Storage Temperature Range	$T_{STG}$	-55 to 150	°C
ESD Capability, Human Body Model (Note 2)	$ESD_{HBM}$	2	kV
ESD Capability, Charge Device Model (Note 2)	$ESD_{CDM}$	500	V
Lead Temperature Soldering Reflow (SMD Styles Only), Pb-Free Versions (Note 3)	$T_{SLD}$	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

- Refer to ELECTRICAL CHARACTERISTICS, RECOMMENDED OPERATING RANGES and/or APPLICATION INFORMATION for Safe Operating parameters.
- This device series incorporates ESD protection and is tested by the following methods:  
 ESD Human Body Model tested per AEC-Q100-002 (EIA/JESD22-A114)  
 ESD Machine Model tested per AEC-Q100-003 (EIA/JESD22-A115)  
 Latchup Current Maximum Rating:  $\leq 100$  mA per JEDEC standard: JESD78
- For information, please refer to our Soldering and Mounting Techniques Reference Manual, SOLDERRM/D

## THERMAL CHARACTERISTICS

Rating	Symbol	Value	Unit
Thermal Characteristics, TSSOP-16 (Note 1) Thermal Resistance, Junction-to-Air (Note 5) Thermal Reference, Junction-to-Case (Note 5)	$R_{\theta JA}$ $R_{\psi JC}$	115	°C/W

- Values based on copper area of 645 mm<sup>2</sup> (or 1 in<sup>2</sup>) of 1 oz copper thickness and FR4 PCB substrate.

## RECOMMENDED OPERATING RANGES

Rating	Symbol	Min	Typ	Max	Unit
BAT Input voltage	$V_{BAT}$	5	18	28	V
Cell voltage (VC1, VC2, VC3, VC4, VC5)	$V_{CELL}$	2		5	V
ODI, UDI voltage	$V_{PRES}$	0		$V_{BAT}$	V
LED voltage (LD1, LD2, LD3, LD4, LD5)	$V_{LED}$	0		$V_{BAT}$	V
ENB voltage	$V_{EN}$	0		$V_{BAT}$	V
Ambient Temperature	$T_A$	-40		85	°C

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

# NCS35011

## DC ELECTRICAL SPECIFICATIONS

Rating	Symbol	Min	Typ	Max	Unit
--------	--------	-----	-----	-----	------

### VOLTAGE MONITORING (VC1, VC2, VC3, VC4, VC5 and BAT)

BAT Voltage Detection Accuracy ( $T_A = 25^\circ\text{C}$ )	$V_{BAT\_QA}$		<75		mV
Cell Voltage Detection Accuracy ( $T_A = 25^\circ\text{C}$ , $VCx = 3\text{V}$ to $4.7\text{V}$ )	$V_{OA}$	-5		5	mV
Cell Voltage Detection Accuracy Across Temperature ( $T_A = -40$ to $85^\circ\text{C}$ )	$V_{OAD}$	-30		30	mV
Overvoltage Detection (OVD) Range (Note 5)	$V_{OVD}$	3.6		4.7	V
Overvoltage Detection Hysteresis (OVH) Range (Note 5)	$V_{OVH}$	50		500	mV
Undervoltage Detection (UVD) Range (Note 5)	$V_{UVD}$	1.5		2.8	V
Undervoltage Detection Hysteresis (UVH) Range (Note 5)	$V_{UVH}$	50		500	mV
BAT Voltage to Active LD1 Pin for SoC Indication	$V_{DET1}$		Table 2		V
BAT Voltage to Active LD1-2 Pin for SoC Indication	$V_{DET2}$		Table 2		V
BAT Voltage to Active LD1-3 Pin for SoC Indication	$V_{DET3}$		Table 2		V
BAT Voltage to Active LD1-4 Pin for SoC Indication	$V_{DET4}$		Table 2		V
BAT Voltage to Active LD1-5 Pin for SoC Indication	$V_{DET5}$		Table 2		V

### SUPPLY AND LEAKAGE CURRENT

Supply Current – Standby mode with no fault and ENB low	$I_{CC}$		4		$\mu\text{A}$
Input Current at VCx pins	$I_{IN}$	-0.1		0.1	$\mu\text{A}$
Supply Current – State of Charge Mode (ENB=3.6V, LDx=0, VCx=4V, $T_A = 25^\circ\text{C}$ )	$I_{SOC}$		26		$\mu\text{A}$

### ODI/UDI OUTPUT PIN, CMOS ACTIVE HIGH OR LOW VERSION

ODI/UDI Active High Across Temperature ( $I_{ODI-H} \leq 5\text{ mA}$ , *Tested with $V_{BAT}=5\text{V}$ )	$V_{ODI-H}$		$*V_{BAT}-1.7$		V
ODI/UDI Active Low Across Temperature ( $I_{ODI-L} \leq 5\text{ mA}$ )	$V_{ODI-L}$		0.1		V

### OUTPUT DRIVE ODI/UDI, OPEN DRAIN NMOS FET ACTIVE ON OR OFF VERSION

Static Drain-Source On-Resistance (nFET On-Resist), $I_{ODI} = 5\text{mA}$ , $T_A = 110^\circ\text{C}$	$R_{DS-ON}$			15	$\Omega$
ODI/UDI Off Current	$I_{ODI-OFF}$			0.1	$\mu\text{A}$

### ENB INPUT

ENB Input Voltage "High"	$V_{EN-H}$		1.5		V
ENB Input Voltage "Low"	$V_{EN-L}$		1.3		V
ENB Pull Down Current	$I_{PD}$		50		k $\Omega$

### LED OUTPUT CURRENT DRIVE

Output Sink Current	$I_{LED-ON}$			10	mA
Output Leakage Current	$I_{LED-OFF}$			0.1	$\mu\text{A}$

## TIMING REQUIREMENTS

Rating	Symbol	Min	Typ	Max	Unit
--------	--------	-----	-----	-----	------

### DELAY TIMER

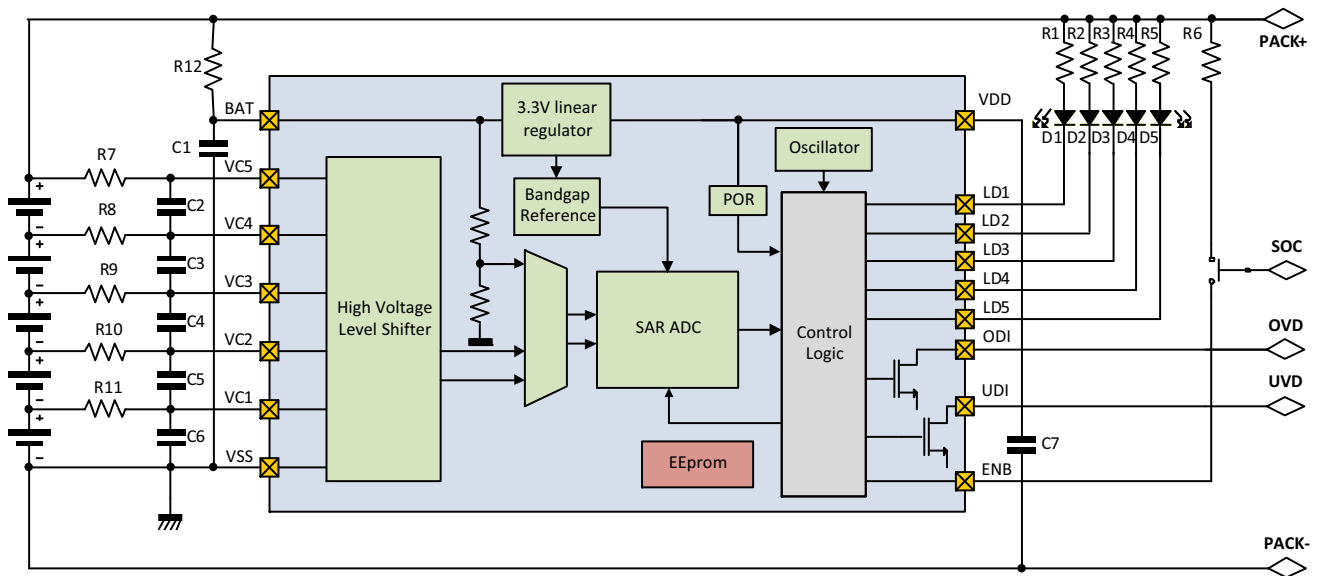
Overvoltage Delay Time (ODEL) Configuration Range (Note 5)	$t_{ODEL}$	0.94	Table 3	5	s
Undervoltage Delay Time (UDEL) Configuration Range (Note 5)	$t_{UDEL}$	0.125	Table 3	1	s
Undervoltage Pulse Time (UPUL) Configuration Range (Note 5)	$t_{UPUL}$	1	Table 3	5	s
Delay/pulse Response Timing Accuracy ( $T_A = 25^\circ\text{C}$ )	$t_{error}$	-6%		6%	
Delay/pulse Response Timing Accuracy Across Temperature ( $T_A = -40$ to $85^\circ\text{C}$ )	$t_{error}$		6%		

### DEBOUNCE/DUTY CYCLE

ENB Debounce for SoC Indication (Note 5)	$t_{ENB}$	30		55	ms
LDx Pulse Duration (LEDD) Time Configuration Range (Note 5)	$t_{LEDD}$	0.05	Table 3	5	s

5. These configurations are programmed at the factory, they are not customer programmable. However, for high volumes, **onsemi** can define further IC variants with any combination of the shown configurations NCS35011DBxyR2G. Contact your sales representative.

# NCS35011



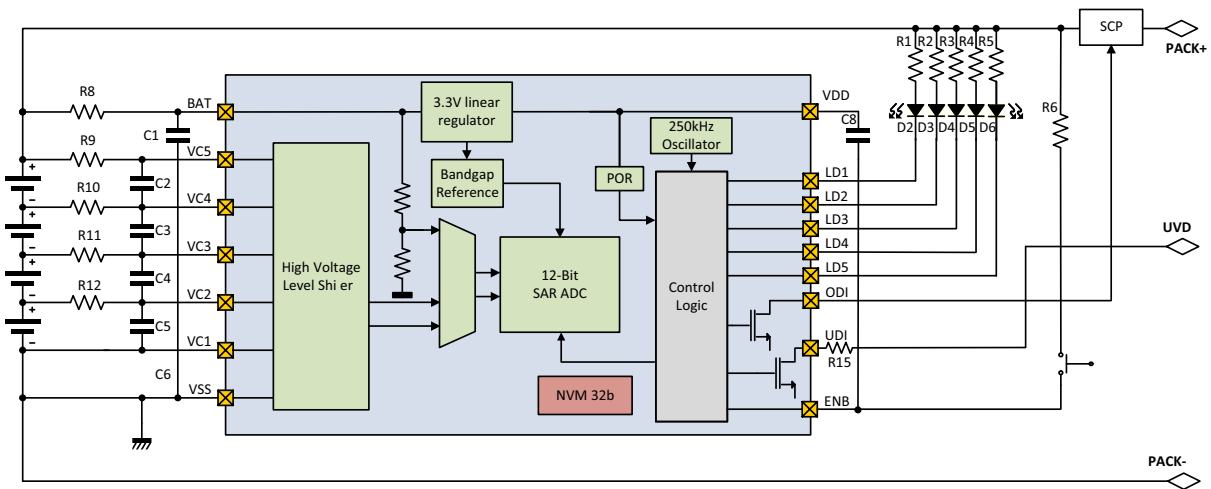
**Figure 3. 5S Battery Pack, 5 LEDs, Open Drain Outputs Application Diagram**

**Table 1. RECOMMENDED EXTERNAL COMPONENTS**

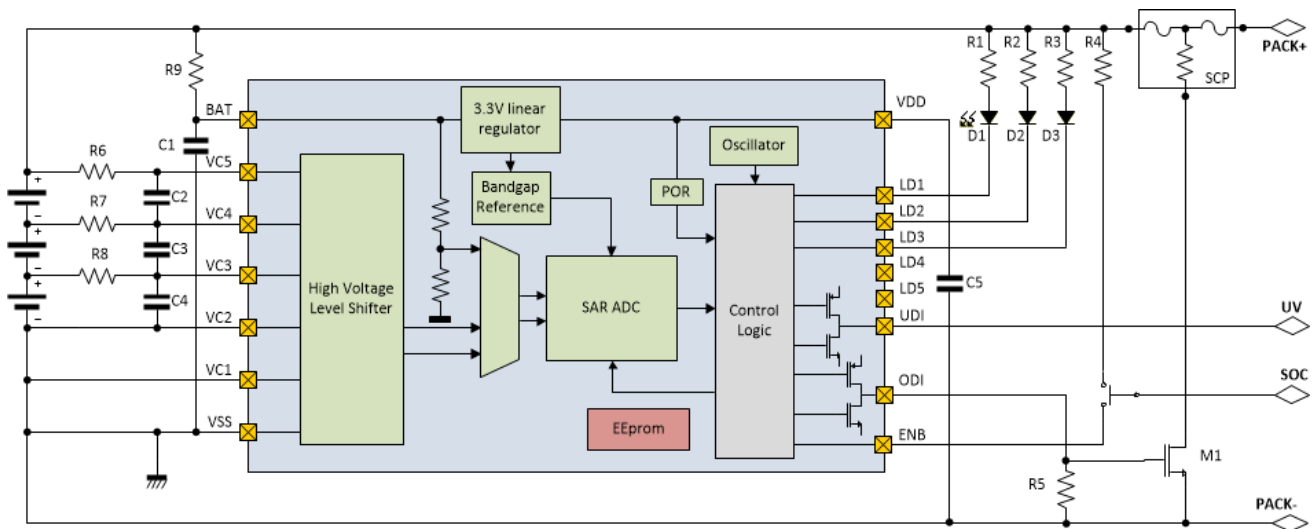
Component Type	Instance	Value	Note
LED	D1,D2,D3,D4,D5	–	LEDs for state of charge indication
Capacitor	C1	1 $\mu$ F	Battery pack voltage capacitor
Capacitor	C2,C3,C4,C5,C6	100 nF	Input cell voltage filter capacitor
Capacitor	C7	1 $\mu$ F	3.3V regulator output filter capacitor
Resistor	R1,R2,R3,R4,R5	4.7 k $\Omega$	LED current limiting resistor, set according to desired brightness; To guarantee the chip spec, it is recommended to limit each LED current less 10 mA.
Resistor	R6	1 k $\Omega$	Limiting resistor for switch input refer to ENB pull-down current spec to set the resistance
Resistor	R7,R8,R9,R10,R11	1 k $\Omega$	Input cell voltage filter resistor
Resistor	R12	1 k $\Omega$	Battery input filter resistor; Limit R12 resistance when IC ODI/UDI pin is configured as CMOS push/pull (Note 6)

6. All VC pin internal high side ESD diodes are connected to BAT pin for ESD protection purpose. When ODI/UDI pin is driving a resistive load and consume a large current through BAT pin, a large IR drop through R12 may result VC5 pin voltage higher than BAT pin and forward bias VC5 pin internal high side ESD diode.

# NCS35011



**Figure 4. 4S Battery Pack, 5 LEDs, Open Drain Outputs with SCP Application Diagram**



**Figure 5. 3S Battery Pack, 3 LEDs, Push-Pull Outputs with SCP Application Diagram**  
**Note: Having series resistor on VC2 and VC1 will help with system level ESD**

## Detailed Description

The NCS35011 is an individual cell-monitoring device that checks for over and under voltage conditions in 3 to 5S battery packs. Figure 3–5 shows the 3, 4, and 5 series of battery pack application diagram, and the IC expect VC1/VC2 to be grounded in 3S and VC1 to be grounded in 4S application. The device also monitors the pack voltage and drives LEDs that indicate the voltage level for a rudimentary state of charge indication.

## Overvoltage and Under-voltage Detection

Monitoring for an overvoltage condition occurs by comparing each cell voltage ( $V_{Cx}$ ) with a predetermined threshold set by the parameter  $V_{OV}$ . An on-chip ADC samples each cell voltages every 125 ms, so this can affect the overvoltage and under-voltage response time. If any cell voltage goes above the  $V_{OV}$  threshold for the predetermined  $t_{DEL-OV}$  time limit, the IC will actuate the ODI pin depending on the pin configuration to indicate a fault. If all of the individual cell voltages drop back down below the  $V_{OV}$  threshold, the ODI pin will default back to the normal operational state. ODI pin will either pull low internally (recommend to limit this current less than 5 mA), if configured as nFET active low, or will be pulled high through external pull-up resistor, if configured as nFET active high impedance; ODI pin can also be configured as CMOS active low or high.

Under-voltage detection occurs by comparing each cell voltage ( $V_{Cx}$ ) with a predetermined threshold set by the parameter  $V_{UV}$ . If any cell voltage goes below the  $V_{UV}$  threshold for the  $t_{DEL-UV}$  time limit, the IC will assert the UDI pin to indicate a fault. A fault indication will assert the UDI pin for the time duration specified by the parameter  $t_{ON-UV}$ . A cell voltage recovery back to a normal level will

not interrupt the UDI signaling. To detect a new under-voltage fault condition all cell voltages will need to return to a normal level and then drop below the  $V_{UV}$  threshold for the specified delay time  $t_{DEL-UV}$ . UDI pin will either pull low internally (recommend to limit this current less than 5mA), if configured as nFET active low, or will be pulled high through external pull-up resistor, if configured as nFET active high impedance; UDI pin can also be configured as CMOS active low or high.

Figure 6 shows timing waveforms of the overvoltage and under-voltage fault detection. Table 1 lists key parameters for each of the fault conditions.

## Battery Pack Voltage State of Charge Indication

When the ENB pin asserts high for the time limit set by  $t_{ENB}$  the NCS37011 will measure the voltage at the BAT pin and compare it to the thresholds set by  $V_{DETX}$ . If the detection level exceeds the predetermined threshold, the appropriate LDx open drain pulldown will assert turning on the corresponding LED for the time duration  $t_{PUL-LED}$  and then shut off. To restart the LEDs the ENB pin will assert low for the time limit  $t_{ENB}$  and then assert high again for the same amount of time. Figure 6 shows the ENB input timing waveform for state of charge indication.

NCS37011 has 4 multiplier sets to choose from, shown in Table 2. The threshold voltage for different LED pin to turn on are dependent upon number of cells ( $VC\_COUNT$ ) in the battery pack and the configured over voltage (OVD) per cell. Each LED threshold is set by multiplying a constant (Multiplier) times the product of  $VC\_COUNT$  and OVD. This creates the typical threshold  $V_{DETX}$ .

$$\text{Product} = VC\_COUNT * OVD;$$

$$V_{DETX} = \text{Product} * \text{Multiplier.}$$

**Table 2.**

SoC Multiplier Sets	LED pin (LDx)	Symbol ( $V_{DETX}$ )	Multiplier
A	LD5	$V_{DET5}$	0.954
	LD4	$V_{DET4}$	0.936
	LD3	$V_{DET3}$	0.898
	LD2	$V_{DET2}$	0.837
	LD1	$V_{DET1}$	0.585
B	LD5	$V_{DET5}$	0.918
	LD4	$V_{DET4}$	0.875
	LD3	$V_{DET3}$	0.847
	LD2	$V_{DET2}$	0.819
	LD1	$V_{DET1}$	0.781
C	LD5	$V_{DET5}$	0.877
	LD4	$V_{DET4}$	0.847
	LD3	$V_{DET3}$	0.788
	LD2	$V_{DET2}$	0.765
	LD1	$V_{DET1}$	0.729

Table 2.

SoC Multiplier Sets	LED pin (LDx)	Symbol ( $V_{DET x}$ )	Multiplier
D	LD5	$V_{DET5}$	0.931
	LD4	$V_{DET4}$	0.883
	LD3	$V_{DET3}$	0.841
	LD2	$V_{DET2}$	0.756
	LD1	$V_{DET1}$	0.659

NOTE: Depends on the application, user may combine or skip certain LED pins to create a desired SoC combination. Unused LED pin can be floated.

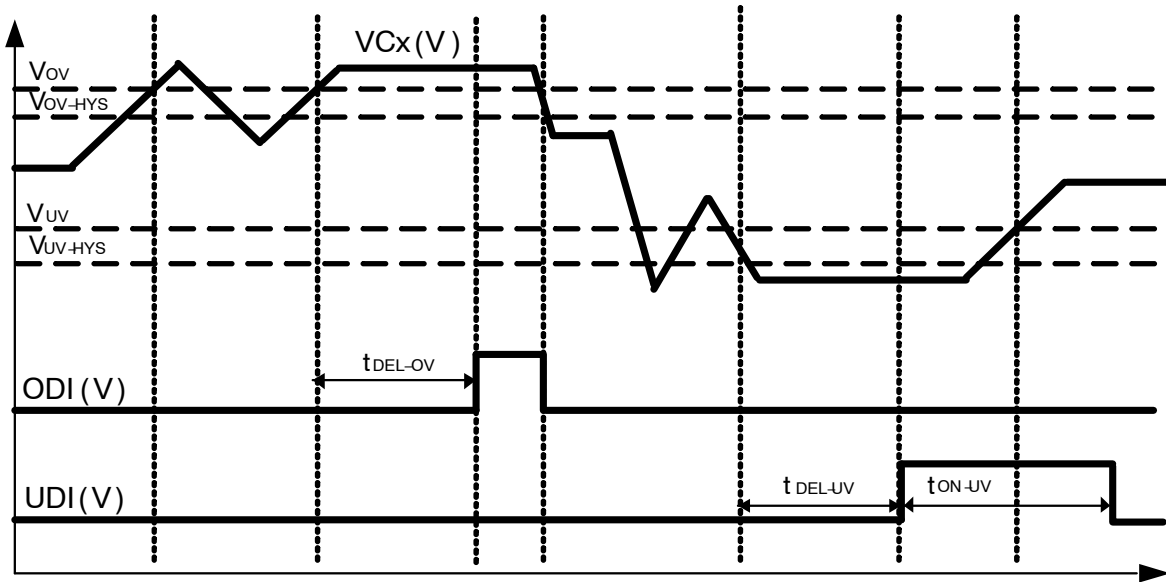


Figure 6. Timing for OV and UV Detection



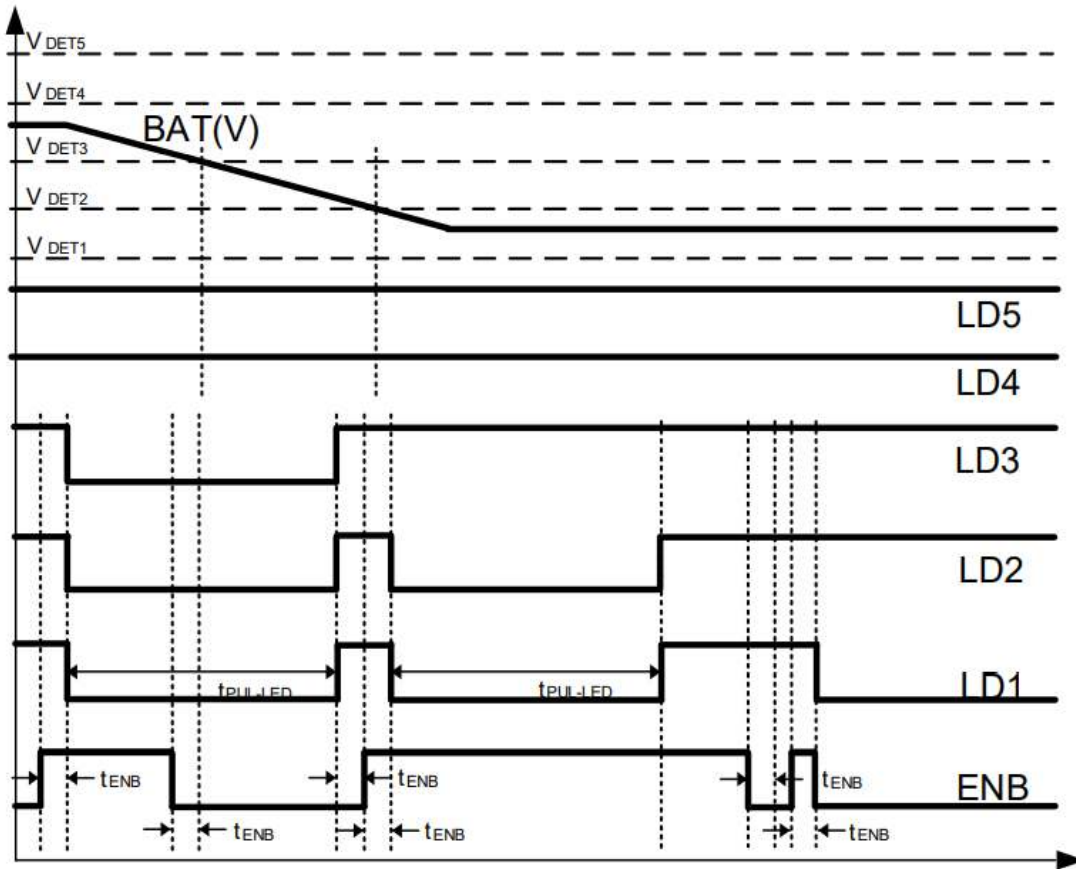


Figure 7. ENB Input Timing for State of Charge Indication

Table 3. ORDERABLE PART DIFFERENTIATION

Part Number	3/4/5 S	OVD (V)	OVH (V)	UVD (V)	UVH (V)	ODEL (s)	UDEL (s)	UPUL (s)	OV Output	OV Polarity	UV Output	UV Polarity	LEDD (s)	SoC sets
NCS35011D-TBR2G	5	4.275	0.05	2	0.25	0.94	1	1.5	OD	1	OD	0	3	A
NCS35011D-TBxyR2G	3-5	3.6-4.7	0.05-0.5	1.5-2.8	0.05-0.5	0.94-4.94	0.125-1	1-5	OD/PP	0/1	OD/PP	0/1	0/3/5	A/B/C/D

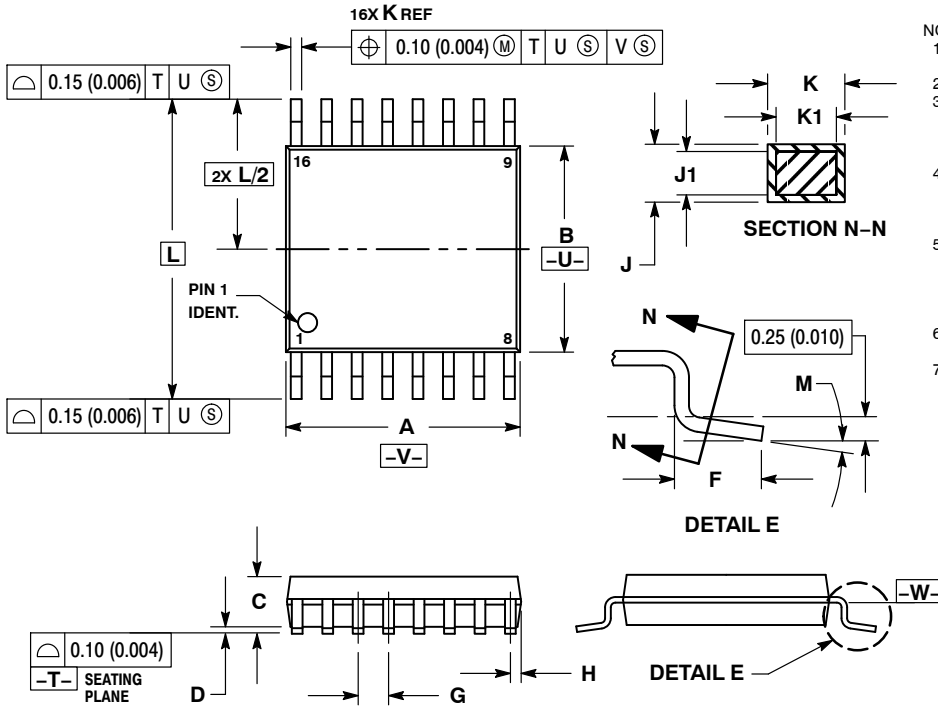
NOTE: **OD** = nFET open drain; **PP** = CMOS push or pull;  
nFET open drain (OV/UV polarity 0): active low (nFET ON);  
nFET open drain (OV/UV polarity 1): active high impedance (nFET OFF);  
CMOS push-pull (OV/UV polarity 0): active low;  
CMOS push-pull (OV/UV polarity 1): active high;

For high volumes, **onsemi** can define further IC variants with any combination of the shown configurations NCS35011DTBxyR2G. Contact your sales representative.

# NCS35011

## PACKAGE DIMENSIONS

TSSOP-16  
CASE 948F  
ISSUE B

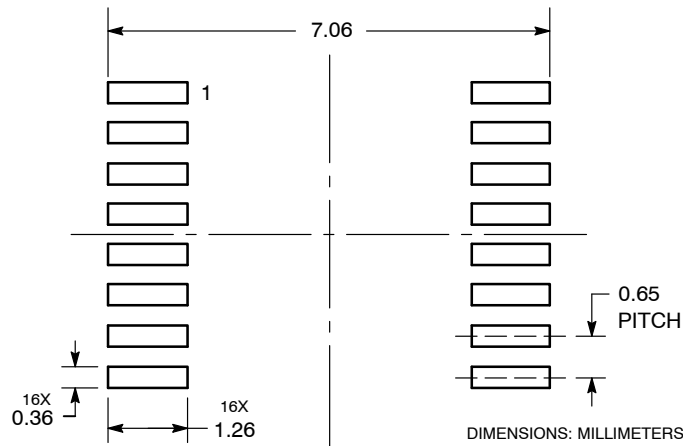


### NOTES:

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: MILLIMETER.
3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.
5. DIMENSION K DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.08 (0.003) TOTAL IN EXCESS OF THE K DIMENSION AT MAXIMUM MATERIAL CONDITION.
6. TERMINAL NUMBERS ARE SHOWN FOR REFERENCE ONLY.
7. DIMENSION A AND B ARE TO BE DETERMINED AT DATUM PLANE -W-.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.90	5.10	0.193	0.200
B	4.30	4.50	0.169	0.177
C	---	1.20	---	0.047
D	0.05	0.15	0.002	0.006
F	0.50	0.75	0.020	0.030
G	0.65 BSC		0.026 BSC	
H	0.18	0.28	0.007	0.011
J	0.09	0.20	0.004	0.008
J1	0.09	0.16	0.004	0.006
K	0.19	0.30	0.007	0.012
K1	0.19	0.25	0.007	0.010
L	6.40 BSC		0.252 BSC	
M	0°	8°	0°	8°

### SOLDERING FOOTPRINT



**onsemi**, **Onsemi**, and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at [www.onsemi.com/site/pdf/Patent-Marking.pdf](http://www.onsemi.com/site/pdf/Patent-Marking.pdf). **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as-is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

## PUBLICATION ORDERING INFORMATION

### LITERATURE FULFILLMENT:

Email Requests to: [orderlit@onsemi.com](mailto:orderlit@onsemi.com)

**onsemi Website:** [www.onsemi.com](http://www.onsemi.com)

### TECHNICAL SUPPORT

**North American Technical Support:**  
Voice Mail: 1 800-282-9855 Toll Free USA/Canada  
Phone: 011 421 33 790 2910

**Europe, Middle East and Africa Technical Support:**

Phone: 00421 33 790 2910

For additional information, please contact your local Sales Representative